RoHS COMPLIANT

Vishay High Power Products

Medium Power Thyristors (Stud Version), 16 A

FEATURES

- · Improved glass passivation for high reliability and exceptional stability at high temperature
- High dl/dt and dV/dt capabilities
- · Standard package
- · Low thermal resistance
- · Metric threads version available
- Types up to 1200 V V_{DRM}/V_{RRM}
- · RoHS compliant
- · Designed and qualified for industrial and consumer level

TYPICAL APPLICATIONS

- Medium power switching
- · Phase control applications
- · Can be supplied to meet stringent military, aerospace and other high reliability requirements

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
1		16	А		
I _{T(AV)}	T _C	85	°C		
I _{T(RMS)}		35	А		
I _{TSM}	50 Hz	340	А		
	60 Hz	360	A		
l ² t	50 Hz	574	A ² s		
	60 Hz	524	A-5		
V _{DRM} /V _{RRM}		100 to 1200	V		
tq	Typical	110	μs		
TJ		- 65 to 125	°C		

16 A

TO-208AA (TO-48)

PRODUCT SUMMARY

I_{T(AV)}



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16RIA Series

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ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE ⁽¹⁾ V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE ⁽²⁾ V	I_{DRM}/I_{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA			
	10	100	150	20			
	20	200	300				
	40	400	500				
16RIA 60		600	700	10			
	80	800	900	10			
	100	1000	1100				
	120	1200	1300				

Notes

⁽¹⁾ Units may be broken over non-repetitively in the off-state direction without damage, if dl/dt does not exceed 20 A/µs

 $^{(2)}$ For voltage pulses with $t_p \leq 5\mbox{ ms}$

PARAMETER	SYMBOL		TEST CONDI	TIONS	VALUES	UNITS
Maximum average on-state current at case temperature	I _{T(AV)}	180° sinusoidal conduction		16 85	A °C	
Maximum RMS on-state current	I _{T(RMS)}			35	А	
		t = 10 ms	No voltage		340	
Maximum peak, one-cycle	less.	t = 8.3 ms	reapplied	Sinusoidal half wave,	360	А
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}		285	A
		t = 8.3 ms	reapplied		300	
		t = 10 ms	No voltage	initial T _J = T _J maximum	574	A ² s
Maximum I ² t for fusing	l ² t	t = 8.3 ms	reapplied		524	
Maximum r tior rusing		t = 10 ms	100 % V _{RRM}		405	
		t = 8.3 ms	reapplied		375	
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied, T _J = T _J maximum		5740	A²√s	
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), T _J = T _J maximum		0.97	V	
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi x I_{T(AV)}), T_J = T_J maximum$		1.24		
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), T _J = T _J maximum		17.9	mΩ	
High level value of on-state slope resistance	r _{t2}	$(I > \pi x I_{T(AV)}), T_J = T_J maximum$		13.6	1115.2	
Maximum on-state voltage	V _{TM}	I _{pk} = 50 A, T _J = 25 °C		1.75	V	
Maximum holding current	Ι _Η	- T _J = 25 °C, anode supply 6 V, resistive load		130		
Latching current	١L			200	mA	



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SWITCHING					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
V _{DRM} ≤ 600 V				200	
Maximum rate of rise	$V_{DRM} \le 800 V$	dl/dt	$\label{eq:transform} \begin{array}{l} T_{J} = T_{J} \text{ maximum, } V_{DM} = Rated \; V_{DRM} \\ Gate \; pulse = 20 \; V, \; 15 \; \Omega, \; t_{p} = 6 \; \mu s, \; t_{r} = 0.1 \; \mu s \; maximum \\ I_{TM} = (2 \; x \; rated \; dI/dt) \; A \end{array}$	180	A/µs
of turned-on current	$V_{DRM} \le 1000 \ V$			160	
	$V_{DRM} \le 1600 \ V$			150	
Typical turn-on time		t _{gt}	T _J = 25 °C, at rated V _{DRM} /V _{RRM} , T _J = 125 °C	0.9	
Typical reverse recovery time		t _{rr}	$T_J = T_J$ maximum, $I_{TM} = I_{T(AV)}$, $t_p > 200 \ \mu$ s, dl/dt = - 10 A/ μ s	4	μs
Typical turn-off time		tq	$\label{eq:tau} \begin{split} T_J = T_J \; maximum, \; I_{TM} = I_{T(AV)}, \; t_p > 200 \; \mu s, \; V_R = 100 \; V, \\ dI/dt = - \; 10 \; A/\mu s, \; dV/dt = 20 \; V/\mu s \; linear \; to \; 67 \; \% \; V_{DRM}, \\ gate \; bias \; 0 \; V \; to \; 100 \; W \end{split}$	110	

Note

+ t_q = 10 μs up to 600 V, t_q = 30 μs up to 1600 V available on special request

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum critical rate of rise	dV/dt	$T_J = T_J$ maximum linear to 100 % rated V_{DRM}	100	V/µs	
of off-state voltage	uv/ut	$T_J = T_J$ maximum linear to 67 % rated V_{DRM}	300 (1)	v/µs	

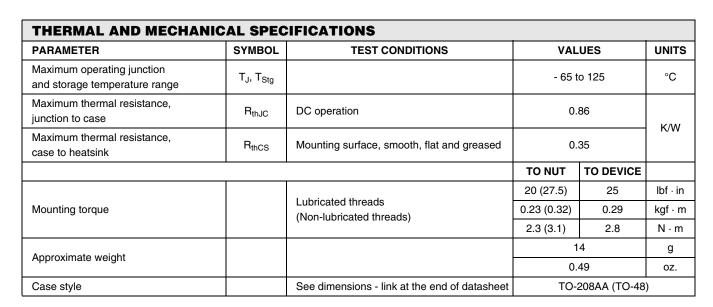
Note

⁽¹⁾ Available with: $dV/dt = 1000 V/\mu s$, to complete code add S90 i.e. 16RIA120S90

TRIGGERING						
PARAMETER	SYMBOL TEST CONDITIONS		VALUES	UNITS		
Maximum peak gate power	P _{GM}	$T_J = T_J maximum$		8.0	w	
Maximum average gate power	P _{G(AV)}			2.0		
Maximum peak positive gate current	I _{GM}	$T_J = T_J maximum$		1.5	А	
Maximum peak negative gate voltage	-V _{GM}	$T_J = T_J$ maximum		10	V	
	I _{GT}	T _J = - 65 °C	Maximum required gate trigger current/voltage are the lowest value which will trigger all units 6 V anode to cathode applied	90	mA	
DC gate current required to trigger		T _J = 25 °C		60		
		T _J = 125 °C		35		
	V _{GT}	T _J = - 65 °C		3.0		
DC gate voltage required to trigger		T _J = 25 °C		2.0	V	
		T _J = 125 °C		1.0		
DC gate current not to trigger I _{GD}		$T_J = T_J$ maximum, V_{DRM} = Rated value		2.0	mA	
DC gate voltage not to trigger	V _{GD}	$T_J = T_J maximum,$ $V_{DRM} = Rated value$	Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.2	V	

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CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS			
180°	0.21	0.15					
120°	0.25	0.25					
90°	0.31	0.34	$T_J = T_J maximum$	K/W			
60°	0.45	0.47					
30°	0.76	0.76					

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

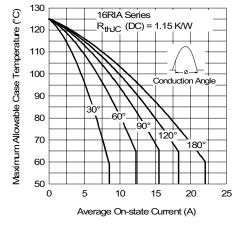


Fig. 1 - Current Ratings Characteristics

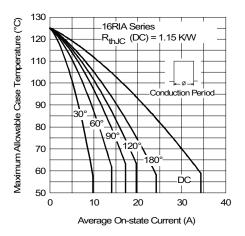


Fig. 2 - Current Ratings Characteristics





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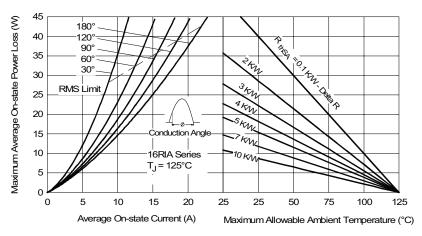


Fig. 3 - On-State Power Loss Characteristics

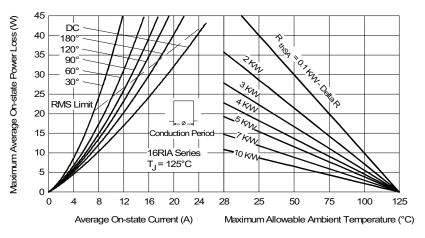


Fig. 4 - On-State Power Loss Characteristics

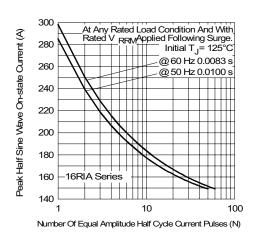


Fig. 5 - Maximum Non-Repetitive Surge Current

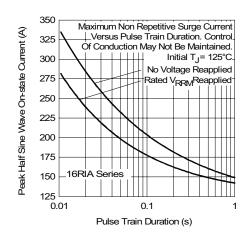


Fig. 6 - Maximum Non-Repetitive Surge Current

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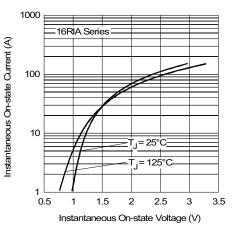
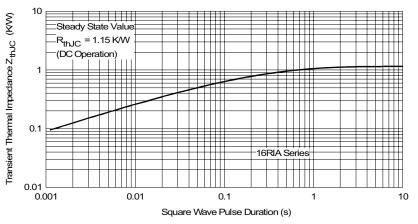
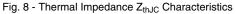
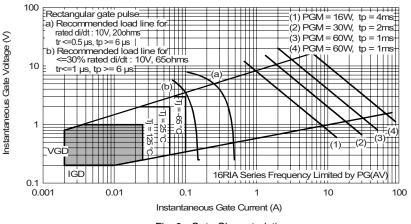


Fig. 7 - Forward Voltage Drop Characteristics







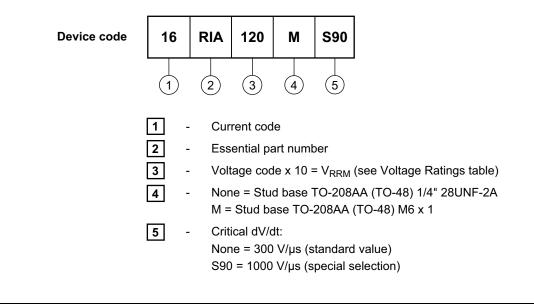


VISHAY



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ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS				
Dimensions	http://www.vishay.com/doc?95333			



Vishay

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